#### CATV 75 $\Omega$ pHEMT Dual RF Amplifier

# TriQuint SEMICONDUCTOR

#### **Applications**

- Replacement for 5 V SOIC-8 Amplifiers
- Edge QAM Output Stage
- MDU Output
- Distribution Amplifiers
- Transmitter Driver Amplifier

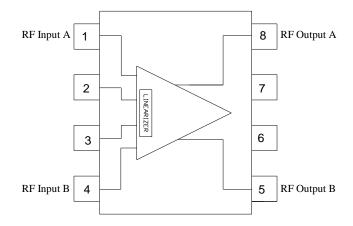
## A POPE

SOIC-8 package

#### **Product Features**

- 75  $\Omega$ , 40-1002 MHz Bandwidth
- pHEMT device technology
- Meets DOCSIS 3.0 Output Requirements
- 5 V supply voltage
- 380 mA typical current consumption
- On-chip Linearization
- SOIC-8 package

## **Functional Block Diagram**



#### **General Description**

The TAT7467H is a 75  $\Omega$  fully integrated single-die differential RF Amplifier covering medium power applications in the CATV band. The TAT7467H includes on-chip linearization to improve  $3^{rd}$  order distortion performance while maintaining low power consumption on a 5 V supply. It is fabricated using 6 inch GaAs pHEMT technology to optimize performance and cost.

## **Pin Configuration**

Pin #	Symbol
1	RF Input A
2	Linearizer A
3	Linearizer B
4	RF Input B
5 6	RF Output B
6	Biasing 2
7	Biasing 1
8	RF Output A
9	Ground Slug

#### **Ordering Information**

Part No.	Description
TAT7467H	75 Ω Dual pHEMT Amplifier (lead-free/RoHS compliant SOIC-8 Pkg)
TAT7467H-EB	Amplifier Evaluation Board

Standard T/R size = 1000 pieces on a 7" reel.

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#### **Specifications**

### **Absolute Maximum Ratings**<sup>1</sup>

Parameter	Rating
Device Voltage	+10 V
Storage Temperature	-60 to +150 °C
Operating Temperature	-40 to +85 °C

#### Notes:

1. Operation of this device outside the parameter ranges given above may cause permanent damage.

#### **Recommended Operating Conditions**

Parameter	Min	Тур	Max	Units
$V_{ m DD}$		5		V
$I_{\mathrm{DD}}$		380		mA
$T_J$ (for > 10 <sup>6</sup> hours MTTF)			145	°C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions

#### **Electrical Specifications**

Test conditions unless otherwise noted: 25 °C case temperature, +5 V V<sub>DD</sub>

Parameter	Conditions	Min	Typical	Max	Units
Operational Frequency Range		50		1002	MHz
Gain			16.5		dB
Gain Flatness	See Note 1		+/- 0.75		dB
Noise Figure			4.7		dB
Input Return Loss			18		dB
Output Return Loss			23		dB
EQAM Output Out-of-band Spurious and Noise for single channel on a single port Vout = 62 dBmV/ch	Adjacent, See Note 2 and Note 3			-62	dBc
P1dB			24		dBm
OIP3	See Note 4		43		dBm
Equivalent Harmonics	See Note 5			-63	dBc
V <sub>SUPPLY</sub>			+5		V
$I_{\mathrm{DD}}$			380		mA
Thermal Resistance (jnc. To case) $\theta_{ic}$			14.5		°C/W

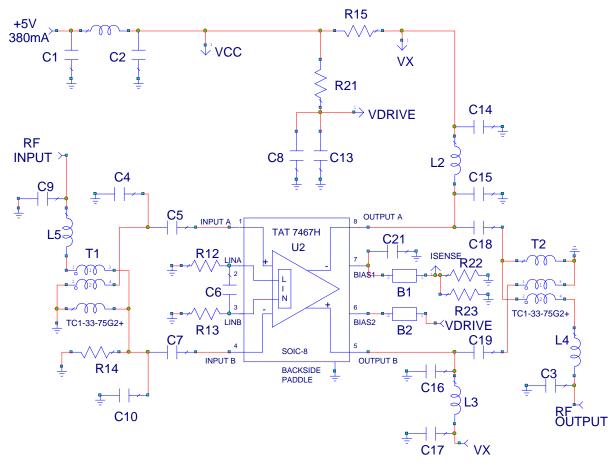
#### Notes

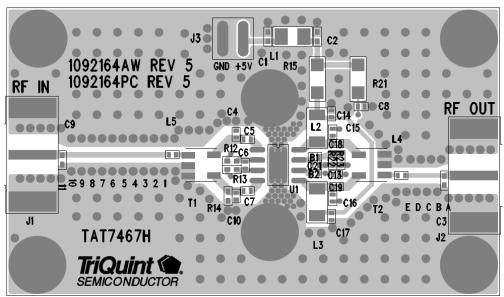
- 1. Peak deviation from straight line across full band.
- 2. Production tested at 66 MHz, 330 MHz, and 990 MHz.
- 3. Adjacent channel (750 kHz from channel block edge to 6 MHz from channel block edge).
- 4. 100 MHz tone spacing at 0 dBm/tone.
- 5. Spurious and noise levels in channels coinciding with 2<sup>nd</sup> harmonic or 3<sup>rd</sup> harmonic.

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## **Application Circuit 50-1002 MHz**







#### Bill of Material: TAT7467H-PCB

Reference Des.	Value	Description	Manuf.	Part Number
U1		75 Ohm RF Amplifier	TriQuint	TAT7467H
L5	2.7nH	Ind, wirewound, 0402, 640 mA, 5%	Various	
T1, T2	1:1	1:1 Balun	Minicircuits	TC1-33-75G2+
C3, C4, C10, C15, C16	0.5pF	Cap, ceramic, 0402, 50 V, +/- 0.25 pF	Various	
C5, C6, C7, C13, C14, C17	0.01uF	Cap, ceramic, 0402, 16 V, 10%	Various	
R12, R13	1.21kΩ	Res, thick film, 0402, 1/16 W, 1%	Various	
R14	750Ω	Res, thick film, 0402, 1/16 W, 1%	Various	
R15	1Ω	Res, thick film, 1206, 5%	Various	
R21	12Ω	Res, thick film, 1206, 5%	Various	
R22, R23	1.5Ω	Res, thick film, 0402, 1/16 W, 1%	Various	
C1, C2	0.1uF	Cap, ceramic, 0402, 16 V, 10%	Various	
L2, L3	500nH	Ind, bead, 1206, 260 mA, 10%	Murata	LQH31HNR50K03
L1	0.9uH	Ind, High Current, 1008, 10%	Coilcraft	1008AF-901XKL
C18, C19	270pF	Cap, ceramic, 0402, 50 V, 10%	Various	
L4	5.6nH	Ind, wirewound, 0402, 760 mA, 5%	Various	
B1, B2	600 Ω	Bead 600 Ω 0402 300 mA	Murata	BLM15HG601SN1
C8, C9, C21	DNP	Do Not Place		

#### **Detailed Device Description**

The TAT7467H is a flexible 5 V differential amplifier for medium power CATV applications. The amplifier of the TAT7467H was specially designed to work with on-chip linearization to provide 3<sup>rd</sup> order distortion improvement over a wide range of RF power levels and across the full CATV bandwidth. Operation of the linearizer will not affect overall gain by more than 0.7 dB.

For any amplifier bias current, output 3<sup>rd</sup> order distortion may be improved by adjusting a small bias current of the on-chip linearization circuit. The Application Schematic shows resistors setting the linearizer currents. Alternate linearizer drive circuitry is possible; consult TriQuint for discussion.

Bias current may be adjusted with changes to external components making the TAT7467H ideal for both input and output gain stages in an EdgeQAM amplifier line-up. For output stage applications, bias currents of between 300 mA to 400 mA are recommended. For input stage applications, bias currents of 230 mA are recommended.

The TAT7467H is built using a single die, which significantly improves its resulting circuit balance and corresponding  $2^{nd}$  order distortion performance. For best  $2^{nd}$  order performance, an input balun using a  $3^{rd}$  wire construction may be used to improve the input phase balance going into the TAT7467H.

The TAT7467H is packaged in an industry standard SOIC-8 package with a large exposed paddle to enable good heatflow to a backside heatsink. At the maximum recommended bias current of 400 mA the power consumption will be 2 W. The

## **TAT7467H**

#### CATV 75 $\Omega$ pHEMT Dual RF Amplifier



TAT7467H is fabricated using a mature pHEMT process that has demonstrated outstanding reliability performance on other TriQuint products. Please consult TriQuint for further information, sjcapplication.engineering@tqs.com.

#### **Package Information and Dimensions**

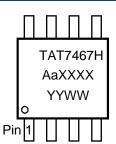
Marking:

Product Number – TAT7467H Assembly Code - AaXXXX Year/Week Code – YYWW

This package is lead-free/RoHS-compliant.

The plating material on the leads is 100% Matte Tin.

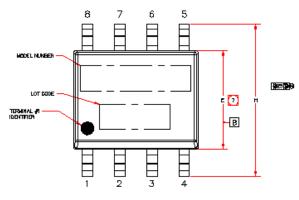
It is compatible with both lead-free (maximum 260 °C reflow temperature) and lead (maximum 245 °C reflow temperature) soldering processes

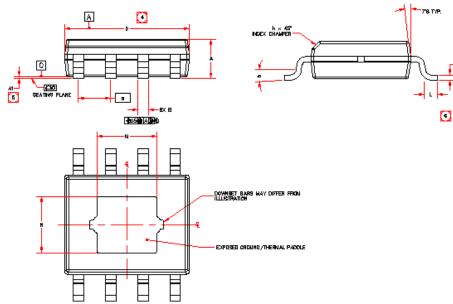


#### **HOTE2b**

- EXCEPT WHERE NOTED, THIS PART OUTLINE CONFORMS TO JEDEC STANDARD NS—012, ESUE C FOR SHALL OUTLINE (SO) PERPHERAL TERMINALS 3/79mm BOOT WOTH (PLASTIC).
- ONENSKINNE & TOLERANCHE CONFORN TO AND Y14.44-1984.
- ALL DIMENSIONS ARE IN NILLIMETERS (INCHES). ANGLES ARE IN DOGRESS.
- DOES NOT INCLIDE NOUD FLASH, PROTRUSIONS OF CATE BURNS, WHICH SHALL NOT EXCEED .16mm(,COSIN) PER SIDE.
- BUTTON PROM JEDEC MS-012 STANDARD.
- B LENGTH OF TERNINAL FOR BOLDERING TO A BUBBITRATE.

		ишиетеля			INCHES		
	5/NBOL	MH	HCM	MAX	MH	NON	WAX
<b>(5)</b>	A	1.42	1.52	1.62	.058	<b>.08</b> 0	A84
	A1	0	.05	.10	٥	1003	.004
0	B	.38	.41	.43	.018	.DIS	.017
-	C	.19	.20	Ħ	.007	.008	.010
	0	4.80	480	6.00	.188	183	.187
	E	180	193	+200	.150	.154	.157
	•		.27 BS	;	.050 890		
	Н	8.80	8.0	8.20	.228	228	244
	h	.28	.33	8	8	.013	702
	L	.40	.54	1.97	þ	þ	/050
6	H	221	234	2.47	.087	.002	A <b>6</b> 7
(O)	Н	209	2.21	234	.092	.087	.092
	н	0	48	E	٥	4'8	ń





#### **TAT7467H**

#### CATV 75 Ω pHEMT Dual RF Amplifier



#### **Product Compliance Information**

#### **ESD Information**



#### **Caution! ESD-Sensitive Device**

ESD Rating: Class 1 B

Value: Passes ≥ 400 V min.

Test: Human Body Model (HBM)

Standard: JEDEC Standard JESD22-A114

ESD Rating: Class IV

Value: Passes ≥ 2000 V min.

Test: Charged Device Model (CDM) Standard: JEDEC Standard JESD22-C101

#### **MSL** Rating

Level 3 at +260 °C convection reflow. The part is rated Moisture Sensitivity Level 3 at 260 °C per JEDEC standard IPC/JEDEC J-STD-020.

#### **Solderability**

Compatible with the latest version of J-STD-020, Lead free solder, 260 °C.

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

#### **Contact Information**

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